# NSN 5961-00-034-5874

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#### **Inclosure Material:**

Metal

**Overall Length:** 

0.360 inches

## **Overall Diameter:**

1.250 inches

#### **End Application:**

Aircraft, hercules c-130

### **Mounting Facility Quantity:**

1

## Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

# Features Provided:

Hermetically sealed case

#### Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, emitter-to-base, collector open and 45.0 breakdown voltage, collector-to-emitter, base open

#### **Current Rating Per Characteristic:**

30.00 amperes source cutoff current and 30.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

170.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Thread Series Designator:**

Unf

#### Terminal Type And Quantity:

2 tab, solder lug and 1 threaded stud

#### **Specification Data:**

80131-release3481 professional/industrial association specification

# Shelf Life:

N/a

# Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

